

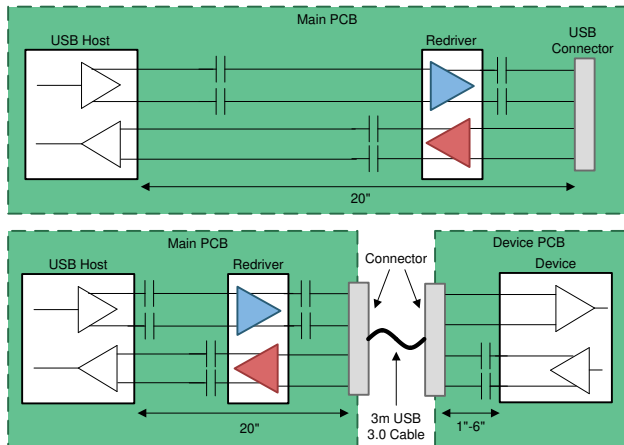
TUSB522P 3.3V 双通道 USB 3.1 GEN 1 转接驱动器、均衡器

1 特性

- 具有 3.3V 电源的 USB3.1 GEN1 5Gbps 双通道转接驱动器
- 超低功耗架构：
 - 有效：98 mA
 - U2、U3：1.2mA
 - 断开：265μA
 - 关断：60μA
- 出色的接收器均衡：
 - 3dB、6dB 和 9dB 三种增益设置 (2.5GHz 时)
- 输出驱动器去加重功能，0dB、3.5dB 和 6dB 三种配置可供选择
- 自动 LFPS 去加重控制，满足 USB 3.1 认证要求
- 无主机或器件端要求
- 支持热插拔
- 工业温度范围：-40°C 至 85°C TUSB522PI
- 商用温度范围：0°C 至 70°C TUSB522P

2 应用

- 手机
- 平板电脑
- 笔记本电脑
- 台式机
- 扩展坞
- 背板和有源电缆



3 说明

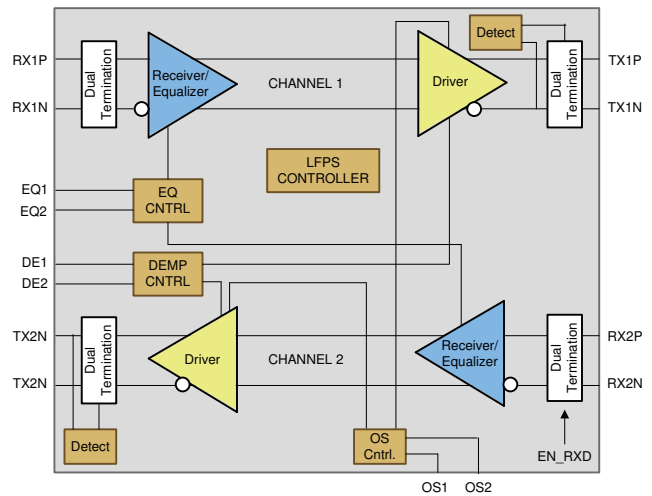
TUSB522P 是一款支持 5Gbps 数据传输速率的第四代双通道单路 USB 3.1 GEN 1 转接驱动器和信号调节器。该器件采用超低功耗架构，在由 3.3V 电源供电运行时功耗非常低。转接驱动器还支持 USB 3.1 低功耗模式，可进一步降低空闲状态下的功耗。

双通道能力使得该系统能够在发送和接收数据路径上保持信号的完整性。接收器均衡有三种增益设置，用以克服插入损耗和码间串扰造成的通道性能退化。这些设置由 EQ 引脚控制。为了补偿传输线路损耗，输出驱动器还支持使用引脚 DE 配置去加重功能。此外，自动 LFPS 去加重控制有助于实现与 USB 3.1 完全兼容。这些设置使得 USB 3.1 第 1 代路径中的 TUSB522P 能够达到最佳性能，并延长信号传输距离以及实现灵活安置。

器件信息

器件型号	温度	封装 ⁽¹⁾
TUSB522P	T _A = 0°C 至 70°C	RGE (VQFN , 24)
TUSB522PI	T _A = -40°C 至 85°C	

(1) 如需了解所有可用封装，请参阅数据表末尾的可订购产品附录。



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简化版原理图



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4 Revision History

注：以前版本的页码可能与当前版本的页码不同

Changes from Revision D (May 2019) to Revision E (November 2023)	Page
• 更新了整个文档中的表格、图和交叉参考的编号格式.....	1
• 更新了 器件信息 表以包含环境温度.....	1
• In the <i>Pin Functions</i> table deleted "Note: When OS = low." for both DE1 and DE2.	3
• In <i>Recommended Operation Conditions</i> , changed C _{AC-USB1} max from 200 nF to 265 nF.....	5
• Reformat Table 7-1 for readability.....	11
• Updated Figure 8-1 to include C _{AC-USB1} , C _{AC-USB2} , L _{AB} , L _{CD} , L _{AC-CAP} , L _{ESD} , R _{ESD} , and R _{RX} ,	12
• Added comment that ac-capacitor should be placed between ESD and USB receptacle when designing for short to VBUS protection.....	12
• Updated the <i>Design Parameters</i> table to include pre-channel and post-channel min/max limits.....	13
• Added the <i>ESD Protection</i> section.....	14
Changes from Revision C (May 2019) to Revision D (May 2019)	Page
• Changed pin 11 From: TX1N To: TX2N and pin 12 From: TX1P To: TX2P in Figure 8-2.....	13
Changes from Revision B (November 2017) to Revision C (May 2019)	Page
• Deleted the RGE0024F mechanical pages.....	17
Changes from Revision A (October 2016) to Revision B (November 2017)	Page
• Changed the values in the FOR OS = HIGH column of Table 7-1 to match FOR OS = LOW column.	11
Changes from Revision * (July 2016) to Revision A (October 2016)	Page
• 将器件从“预发布”更改为“量产”.....	1

5 Pin Configuration and Functions

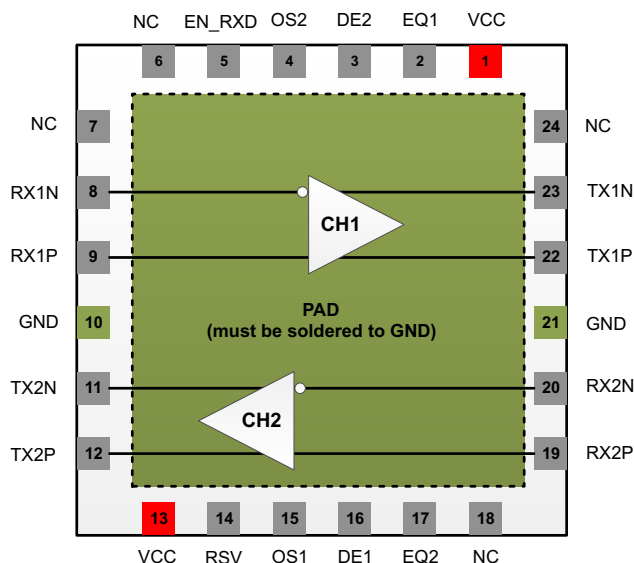


图 5-1. RGE Package, 24-Pin (VQFN) (Top View)

表 5-1. Pin Functions

PIN		I/O	DESCRIPTION
NAME	NO.		
RX1N	8	Differential I	Differential input for 5Gbps negative signal on Channel 1
RX1P	9	Differential I	Differential input for 5Gbps positive signal on Channel 1
TX1N	23	Differential O	Differential output for 5Gbps negative signal on Channel 1
TX1P	22	Differential O	Differential output for 5Gbps positive signal on Channel 1
RX2N	20	Differential I	Differential input for 5Gbps negative signal on Channel 2
RX2P	19	Differential I	Differential input for 5Gbps positive signal on Channel 2
TX2N	11	Differential O	Differential output for 5Gbps negative signal on Channel 2
TX2P	12	Differential O	Differential output for 5Gbps positive signal on Channel 2
EQ1	2	I, CMOS	Sets the receiver equalizer gain for Channel 1. 3-state input with integrated pull-up and pull-down resistors. EQ1 = Low = 3 dB EQ1 = Mid = 6 dB EQ1 = High = 9 dB
DE1	16	I, CMOS	Sets the output de-emphasis for Channel 1. 3-state input with integrated pull-up and pull-down resistors. DE1 = Low = 0 dB DE1 = Mid = -3.5 dB DE1 = High = -6.2 dB
OS1	15	I, CMOS	Sets the output swing (differential voltage amplitude) for Channel 1. 2-state input with an integrated pull down resistor. OS1 = Low = 0.9 mV OS1 = High = 1.1 mV
EQ2	17	I, CMOS	Sets the receiver equalizer gain for Channel 2. 3-state input with integrated pull-up and pull-down resistors. EQ2 = Low = 3 dB EQ2 = Mid = 6 dB EQ2 = High = 9 dB

表 5-1. Pin Functions (续)

PIN		I/O	DESCRIPTION
NAME	NO.		
DE2	3	I, CMOS	Sets the output de-emphasis for Channel 2. 3-state input with integrated pull-up and pull-down resistors. DE2 = Low = 0 dB DE2 = Mid = -3.5 dB DE2 = High = -6.2 dB
OS2	4	I, CMOS	Sets the output swing (differential voltage amplitude) for Channel 2. 2-state input with an integrated pull down resistor. OS2 = Low = 0.9 mV OS2 = High = 1.1 mV
EN_RXD	5	I, CMOS	Enable. The device has a 660-k Ω pulldown resistor. Device is active when EN_RXD = High. Drive actively high or install a pullup resistor (recommend 4.7 K Ω) for normal operation. Does reset state machine.
RSV	14	I, CMOS	Reserved. Can be left as no-connect.
VCC	1, 13	P	Positive power supply. Power supply is 3.3 V.
GND	10, 21, PAD	G	Ground. PAD must be connected to Ground. Pins 10, 21 can be connected to Ground or left unconnected.
NC	6, 7, 18, 24	—	No connection. These pins can be tied to any desired voltages including connecting them to GND.

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
Supply Voltage Range ⁽²⁾	V _{CC}	– 0.5	4	V
Voltage Range at any input or output terminal	Differential I/O	– 0.5	1.5	V
	CMOS Inputs	– 0.5	4	V
Junction temperature, T _J			105	°C
Storage temperature, T _{stg}		– 65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values are with respect to the GND terminals.

6.2 ESD Ratings

		VALUE	UNIT
V _(ESD) Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000	V
	Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±500	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

			MIN	NOM	MAX	UNIT
V _{CC}	Main power supply		3	3.3	3.6	V
	Supply Ramp Requirement				100	ms
V _(PSN)	Supply Noise on V _{CC} Terminals				100	mV
T _A	Operating free-air temperature	TUSB522P	0		70	°C
		TUSB522PI	– 40		85	°C
C _{AC-USB1}	External AC coupling capacitor		75	100	265	nF

6.4 Thermal Information

THERMAL METRIC ⁽¹⁾		TUSB522P	UNIT
		RGE (VQFN)	
		24 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	51.2	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	55.9	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	28.3	°C/W
ψ_{JT}	Junction-to-top characterization parameter	2.0	°C/W
ψ_{JB}	Junction-to-board characterization parameter	28.3	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	9.7	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

6.5 Electrical Characteristics, Power Supply

over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$I_{CC(ACTIVE)}$	Average active current	Link in U0 with GEN1 data transmission. RSV, EQ cntrl pins = NC, EN_RXD = V_{CC} , k28.5 pattern at 5Gbps, $V_{ID} = 1000$ mVpp, OS = 900 mV and DE = 3.5 dB		98	mA
$I_{CC(U2U3)}$	Average current in U2/U3	Link in U2 or U3		1.2	mA
$I_{CC(NC)}$	Average current disconnect mode	Link in Disconnect mode		265	μA
$I_{CC(SHUTDOWN)}$	Average shutdown current	EN_RXD = L		60	μA

6.6 Electrical Characteristics, DC

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
3-State CMOS Inputs(EQ1/2, DE1/2)						
V _{IH}	High-level input voltage		V _{CC} × 0.8			V
V _{IM}	Mid-level input voltage		V _{CC} / 2.			V
V _{IL}	Low-level input voltage		V _{CC} × 0.2			V
V _F	Floating voltage	V _{IN} = High impedance	0.36 × V _{CC}			V
R _{PU}	Internal pull-up resistance		410			k Ω
R _{PD}	Internal pull-down resistance		240			k Ω
I _{IH}	High-level input current	V _{IN} = 3.6 V			26	μA
I _{IL}	Low-level input current	V _{IN} = GND, V _{CC} = 3.6 V	- 26			μA
2-State CMOS Input (OS1/2, EN_RXD)						
V _{IH}	High-level input voltage		V _{CC} × 0.7			V
V _{IL}	Low-level input voltage		V _{CC} × 0.3			V
R _{PD}	Internal pull-down resistance		660			k Ω
I _{IH}	Low-level input current	V _{IN} = 3.6 V			25	μA
I _{IL}	Low-level input current	V _{IN} = GND, V _{CC} = 3.6 V	- 10			μA

6.7 Electrical Characteristics, AC

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
Differential Receiver (RXP, RXN)						
$V_{(RX-DIFF-PP)}$	Input differential voltage swing.	AC-coupled differential peak-to-peak signal measured post CTLE through a reference channel	100		1200	mVpp
$V_{(RX-DC-CM)}$	Common-mode voltage bias in the receiver (DC)			0.7		V
$R_{(RX-DIFF-DC)}$	Differential input impedance (DC)	Present after a GEN1 device is detected on TXP/TXN	72		120	Ω
$R_{(RX-CM-DC)}$	Receiver DC Common Mode impedance		18		30	Ω
$Z_{(RX-HIGH-IMP-DC-POS)}$	Common-mode input impedance with termination disabled (DC)	Present when no GEN1 device is detected on TXP/TXN. Measured over the range of 0-500 mV with respect to GND.	25			k Ω
$V_{(RX-SIGNAL-DET-DIFF-PP)}$	Input Differential peak-to-peak Signal Detect Assert Level	At 5Gbps, no input channel loss clock pattern		85		mV
$V_{(RX-IDLE-DET-DIFF-PP)}$	Input Differential peak-to-peak Signal Detect De-assert Level			85		mV
$V_{(RX-LFPS-DET-DIFF-PP)}$	Low Frequency Periodic Signaling (LFPS) Detect Threshold	Below the minimum is squelched.	100		300	mV
$V_{(RX-CM-AC-P)}$	Peak RX AC common mode voltage	Measured at package pin			150	mV
$V_{(detect)}$	Voltage change to allow receiver detect	Positive voltage to sense receiver termination			600	mV
$C_{(RX-PARASITIC)}$	Voltage change to allow receiver detect	At 2.5 GHz	0.17	0.63	0.99	pF
$R_{L(RX-DIFF)}$	Differential Return Loss	50 MHz - 1.25 GHz at 90 Ω		- 19		dB
		2.5 GHz at 90 Ω		- 14		dB
$R_{L(RX-CM)}$	Common Mode Return Loss	50 MHz - 1.25 GHz at 90 Ω		- 13		dB
Differential Transmitter (TXP, TXN)						
$V_{(TX-DIFF-PP)}$	Transmitter differential voltage swing (transition-bit)	OS Low, 0dB DE	0.8	0.9		Vpp
		OS High, 0dB DE		1.1	1.2	Vpp
$V_{(TX-DIFF-PP-LFPS)}$	LFPS differential voltage swing	OS Low, High	0.8		1.2	Vpp
$V_{(TX-DE-RATIO)}$	Transmitter differential voltage De-Emphasis ratio	DE = Low		0		dB
		DE = Floating		- 3.5		dB
		DE = High		- 6.2		dB
$V_{(TX-RCV-DETECT)}$	Amount of voltage change allowed during Receiver Detection				600	mV
$V_{(TX-CM-IDLE-DELTA)}$	Transmitter idle common-mode voltage change while in U2/U3 and not actively transmitting LFPS		- 600		600	mV
$V_{(TX-DC-CM)}$	Common-mode voltage bias in the transmitter (DC)			0.7		V
$V_{(TX-CM-AC-PP-ACTIVE)}$	Tx AC Common-mode voltage active	Max mismatch from Txp + Txn for both time and amplitude			100	mVpp
$V_{(TX-IDLE-DIFF-AC-PP)}$	AC Electrical idle differential peak-to-peak output voltage	At package pins	0		10	mV
$V_{(TX-IDLE-DIFF-DC)}$	DC Electrical idle differential output voltage	At package pins after low pass filter to remove AC component	0		10	mV
$V_{(TX-CM-DC-ACTIVE-IDLE-DELTA)}$	Absolute DC common mode voltage between U1 and U0	At package pin			200	mV
$C_{(TX)}$	TX input capacitance to GND	At 2.5 GHz			1.25	pF
$R_{(TX-DIFF)}$	Differential impedance of the driver		72		120	Ω
$R_{(TX-CM)}$	Common-mode impedance of the driver	Measured with respect to AC ground over 0-500 mV	18		30	Ω
$I_{(TX-SHORT)}$	TX short circuit current	TX± shorted to GND			60	mA
$C_{(TX-PARASITIC)}$	TX input capacitance for return loss	Package Pins		0.63	1.02	F

6.7 Electrical Characteristics, AC (续)

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
R _{L(RX-DIFF)}	Differential Return Loss	50 MHz - 1.25 GHz at 90 Ω		12		dB
		1.25 - 2.5 GHz at 90 Ω		8		dB
R _{L(RX-CM)}	Common Mode Return Loss	50 MHz - 1.25 GHz at 90 Ω		13		dB
		1.25 - 2.5 GHz		11		dB
AC Characteristic						
Xtalk	Differential Cross Talk between TX and RX signal Pairs	At 2.5 GHz		- 40		dB
V _(CM-TX-AC)	AC Common-mode voltage swing in active mode	Within U0 and within LFPS			100	mVpp
V _(TX-IDLE-DIFF -AC-PP)	Differential voltage swing during electrical idle	Tested with a high-pass filter	0		10	V
R _{L(TX-DIFF)}	Differential Return Loss	f = 50 MHz - 1.25 GHz		12		dB
		1.25 - 2.5 GHz		8		dB
R _{L(TX-CM)}	Common Mode Return Loss	f = 50 MHz - 1.25 GHz		16		dB
		1.25 - 2.5 GHz		13		dB
t _j	Total Jitter	Minimum input and output trace at 2.5 GHz, V _{CC} = 3.3 V		15		ps
V _(TX-CM- Δ U1-U0)	Absolute delta of DC CM voltage during active and idle states				100	mV
V _(TX-IDLE-DIFF-DC)	DC Electrical idle differential output voltage	Voltage must be low pass filtered to remove any AC component	0		12	mV

7 Detailed Description

7.1 Overview

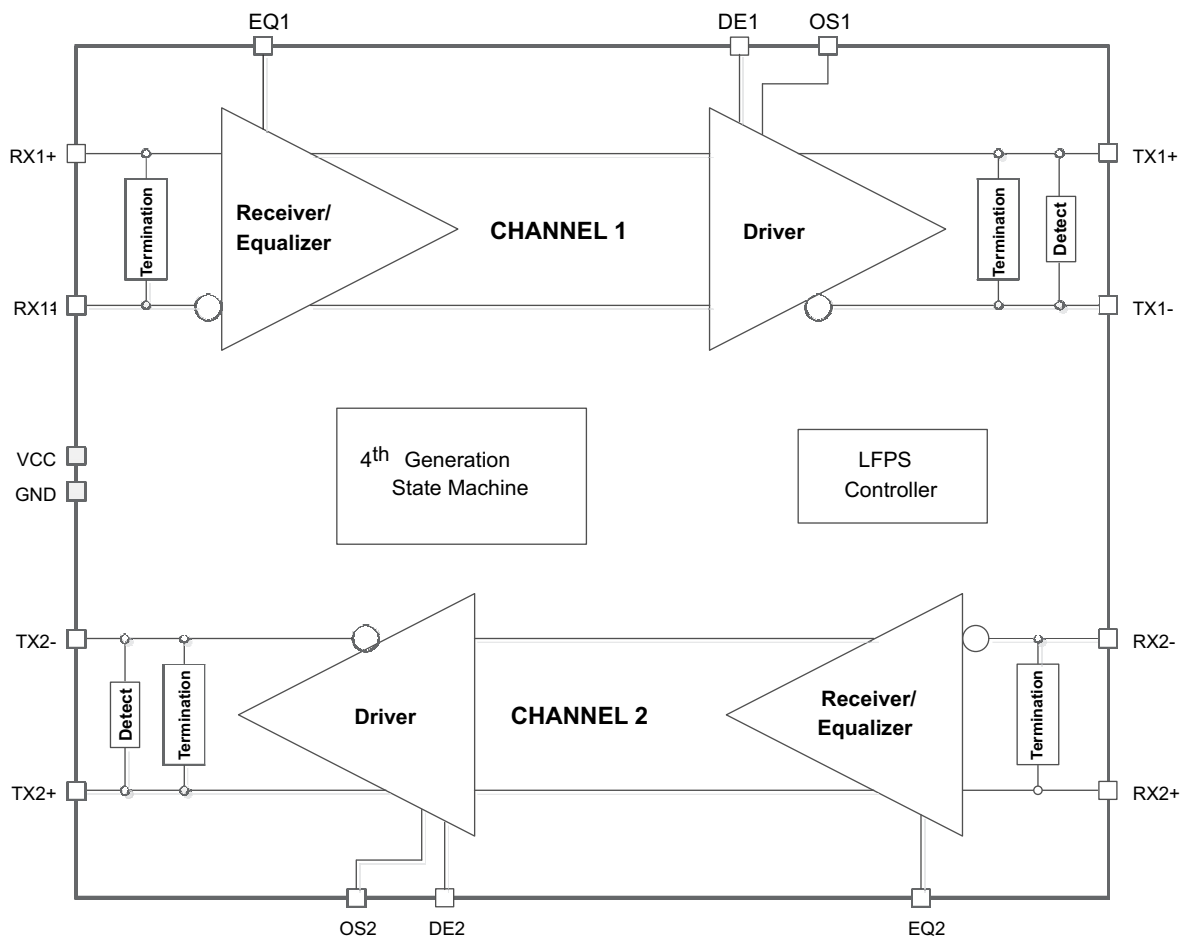
The TUSB522P is designed to overcome channel loss due to inter-symbol interference and crosstalk when 5Gbps USB3.1 GEN1 signals travel across a PCB or cable. The dual channel architecture is a one-chip, low-power solution, extending the possible channel length for transmit and receive data paths in an application. For a Host application, this enables the system to pass both transmitter compliance and receiver jitter tolerance tests.

The re-driver recovers incoming data by applying equalization that compensates for channel loss, and drives out signals with a high differential voltage. Each channel has a receiver equalizer with selectable gain settings. The equalization should be set based on the amount of insertion loss in channel 1 or 2 before the TUSB522P receivers. Likewise, the output drivers support configuration of De-Emphasis. Independent equalization and de-emphasis control for each channel can be set using EQ1/2 and DE1/2 pins.

The TUSB522P advanced state machine makes it transparent to hosts and devices. After power up, the TUSB522P periodically performs receiver detection on the TX pairs. If it detects a USB3.1 GEN1 receiver, the RX termination is enabled, and the TUSB522P is ready to re-drive.

The device ultra-low-power architecture operates at a 3.3-V power supply and achieves Enhanced performance. The automatic LFPS De-Emphasis control further enables the system to be USB3.1 compliant.

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Receiver Equalization

The purpose of receiver equalization is to compensate for channel insertion loss and inter-symbol interference in the system before the input of the TUSB522P. The receiver overcomes these losses by attenuating the low frequency components of the signals with respect to the high frequency components. The proper gain setting should be selected to match the channel insertion loss before the input of the TUSB522P receivers. The gain setting may differ for channel 1 and channel 2.

7.3.2 De-Emphasis Control and Output Swing

The differential driver output provides selectable de-emphasis and output swing control in order to achieve USB3.1 compliance. The TUSB522P offers a unique way to adjust output de-emphasis and transmitter swing based on the OS1/2 and DE1/2 pins. The level of de-emphasis required in the system depends on the channel length after the output of the re-driver. The output swing and de-emphasis levels may differ for channel 1 and channel 2.

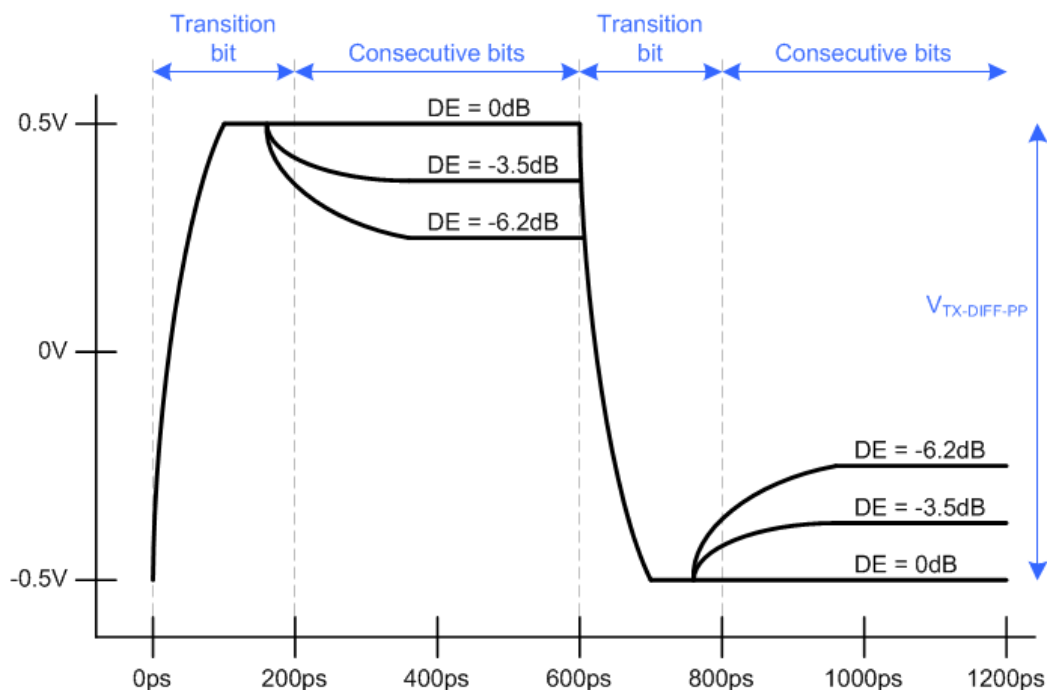


图 7-1. Transmitter Differential Voltage, OS = Floating

7.3.3 Automatic LFPS Detection

The TUSB522P features an intelligent low frequency periodic signaling (LFPS) controller. The controller senses the low frequency signals and automatically disables the driver de-emphasis, for full USB3.1 compliance.

7.4 Device Functional Modes

7.4.1 Device Configuration

表 7-1. Control Pin Settings (Typical Values)

PIN	DESCRIPTION	LOGIC STATE	TYP	UNITS
EQ1/EQ2	Receiver equalization amount	Low	3	dB
		Floating	6	dB
		High	9	dB
OS1/OS2	Transmit output swing amplitude for the transition bit	Low	0.9	Vpp
		High	1.1	Vpp
DE1/DE2	Transmit de-emphasis amount	Low	0	dB
		Floating	– 3.5	dB
		High	– 6.2	dB

7.4.2 Power Modes

The TUSB522P has 3 primary power modes:

7.4.2.1 U0 Mode (Active Power Mode)

During active power mode, U0, the device is transmitting USB SS data or USB LFPS signaling. The U0 mode is the highest power state of the TUSB522P. Anytime super-speed traffic is being received, the TUSB522P remains in this mode.

7.4.2.2 U2/U3 (Low Power Mode)

While in this mode, the TUSB522P periodically performs far-end receiver detection.

7.4.2.3 Disconnect Mode - RX Detect

In this state, the TUSB522P periodically checks for far-end receiver termination on both TX. Upon detection of the far-end receiver's termination on both ports, the TUSB522P will transition to U0 mode.

7.4.2.4 Shutdown Mode

Shutdown mode is entered when the EN_RXD pin is driven low. This is lowest power setting for the device.

8 Application and Implementation

备注

以下应用部分中的信息不属于 TI 器件规格的范围，TI 不担保其准确性和完整性。TI 的客户应负责确定器件是否适用于其应用。客户应验证并测试其设计，以确保系统功能。

8.1 Application Information

The TUSB522P is a dual-channel single-lane re-driver and signal conditioner designed to compensate for ISI jitter caused by attenuation through passive mediums such as traces or cables. The TUSB522P has two independent channels to allow optimization in both upstream and downstream directions through three EQ and six De-Emphasis settings.

8.2 Typical Application

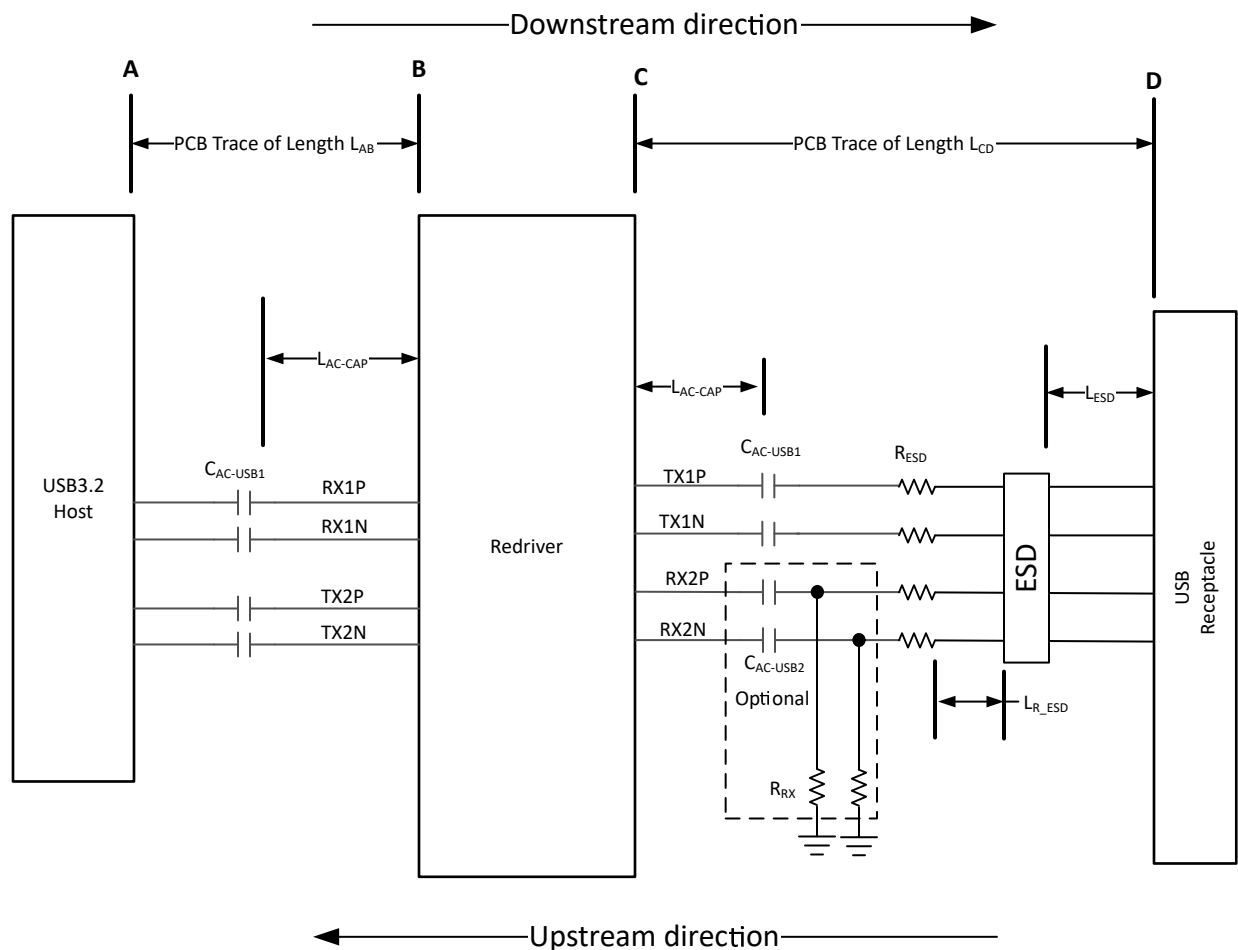


图 8-1. Embedded Host Application

The $C_{AC-USB1}$ and $C_{AC-USB2}$ should be placed between ESD and USB receptacle for systems designing for short to VBUS protection.

8.2.1 Design Requirements

For this design example, use the parameters provided in 表 8-1.

表 8-1. Design Parameters

PARAMETER	VALUE
Pre-channel A to B PCB trace length ⁽¹⁾ , L_{AB} .	1 inches $\leq L_{AB} \leq$ 20 inches
Post-channel C to D PCB trace length ⁽¹⁾ , L_{CD} .	$\leq$ 6 inches
Minimum distance of the AC capacitors from TUSB522P, L_{AC-CAP}	0.25 inches
Maximum distance of ESD component from the USB receptacle, L_{ESD}	0.6 inches
Maximum distance of series resistor (R_{ESD}) from ESD component, L_{R_ESD} .	0.25 inches
$C_{AC-USB1}$ AC-coupling capacitor (75 nF to 265 nF)	100 nF
$C_{AC-USB2}$ AC-coupling capacitor (297 nF to 363 nF)	Options: - RX1 or RX2 are DC-coupled to USB receptacle 330 nF AC-couple with R_{RX} resistor
Optional R_{RX} resistor (220-k $\Omega \pm 5\%$)	Not used
Optional R_{ESD} (0- Ω to 2.2- Ω)	Not used
V_{CC} supply (3-V to 3.6-V)	3.3-V
EQ1 for RX1P/N (3, 6, or 9dB)	9 dB (EQ1 = High)
De-Emphasis 2 for TX2P/N (0, -3.5, and -6.2 dB)	-6.2 dB (OS2 = Low, DE2 = High)
EQ2 for RX2P/N (3, 6, or 9 dB)	6 dB (EQ2 = Floating)
De-Emphasis 1 for TX1P/N (0, -3.5, and -6.2 dB)	-3.5 dB (OS1 = Low, DE1 = Floating)
Output Swing 1 (0.9 or 1.1 Vppd)	900 mV (OS1 = Low)
Output Swing 2 (0.9 or 1.1 Vppd)	900 mV (OS2 = Low)

(1) Maximum trace length assumes an insertion loss of 0.2 dB/inch/GHz. If insertion loss is more than 0.2 dB/inch/GHz, then maximum trace length must be reduced accordingly.

8.2.2 Detailed Design Procedure

The TUSB522P differential receivers and transmitters have internal BIAS and termination. Due to this, the TUSB522P must be connected to the USB Host and receptacle through ac-coupling capacitors. In this example, as depicted in 图 8-2, 100 nF capacitors are placed on TX2P, TX2N, RX1P, RX1N, TX1P and TX1N. No ac-coupling capacitors are placed on the RX2P and RX2N pins because it is assumed the device downstream of the TUSB522P will have ac-coupling capacitors on its transmitter as defined by the USB 3.1 specification. The system designer may desire to support short to VBUS protection. If this is the case, then a 330 nF ac-coupling capacitor should be placed on RX2P/N pins.

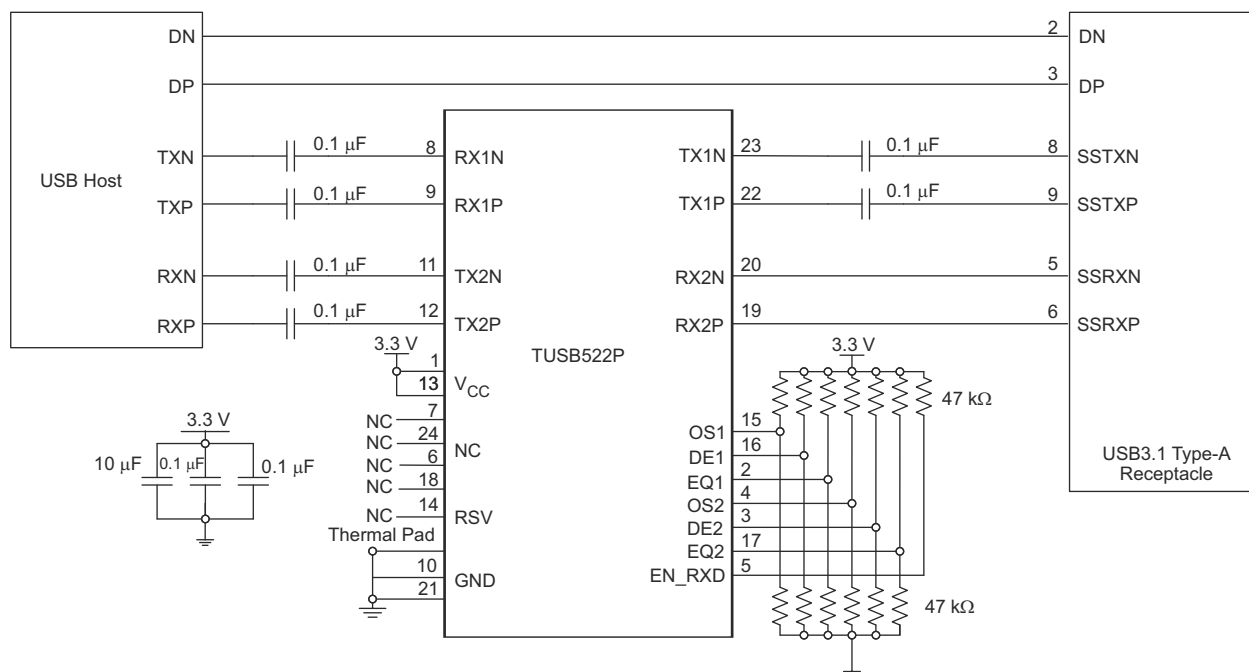


图 8-2. Embedded Host Application Schematic

8.2.2.1 ESD Protection

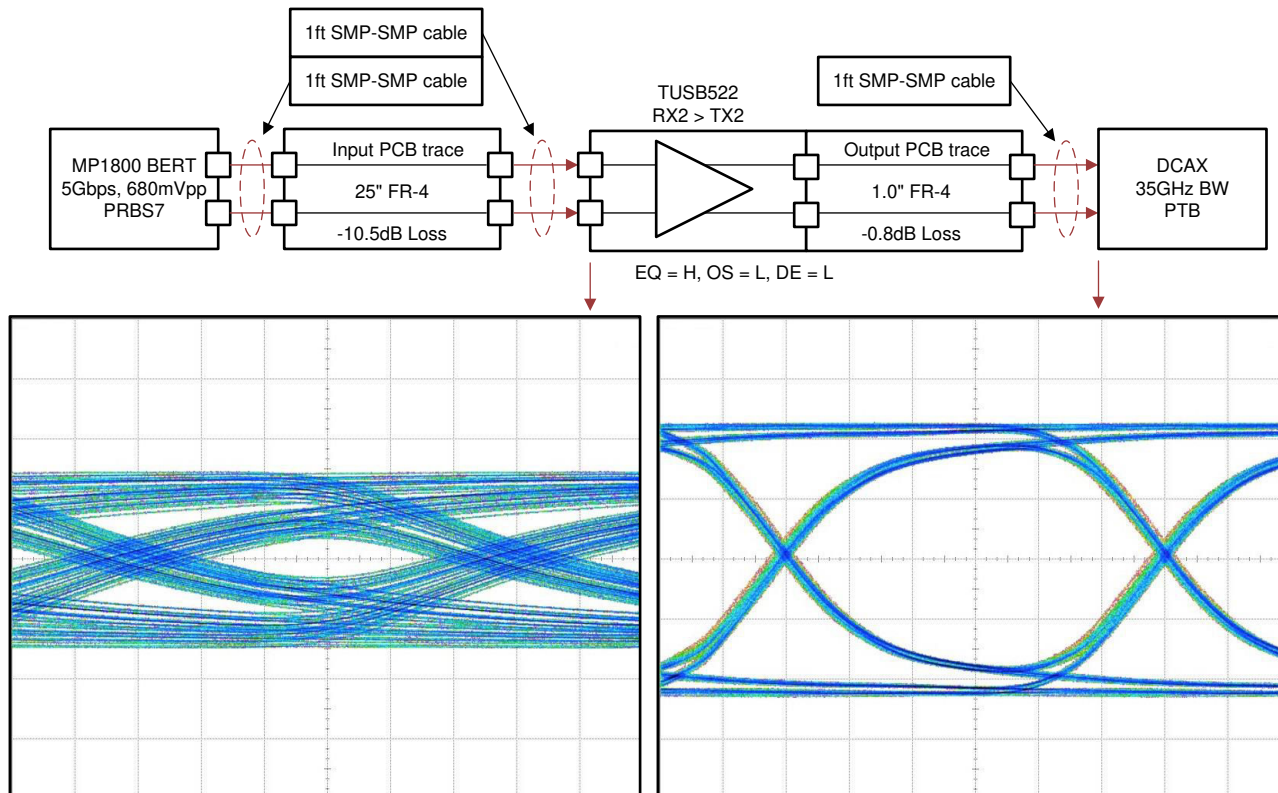
It may be necessary to incorporate an ESD component to protect the TUSB522P from electrostatic discharge (ESD). It is recommended that the ESD protection component has working peak voltage of ≥ 1.3 V, a breakdown voltage of ≥ 2.3 V, and a clamp voltage of ≤ 4.0 V. A clamp voltage greater than 4.0 V may require a R_{ESD} on each differential pin. The ESD component should be placed near the USB connector.

表 8-2. Recommended ESD Protection Component

Manufacturer	Part Number	Required R_{ESD} to pass IEC 61000-4-2 Contact ± 8 -kV
Nexperia	PUSB3FR4	2.2- Ω
Nexperia	PESD2V8Y1BSF	2.2- Ω

8.2.3 Application Curves

BERT > 24"6mil > char-board > RX2-to-TX2 > char-board > Scope



8.3 Power Supply Recommendations

The TUSB522P is designed to operate with a 3.3-V power supply. Levels above those listed in the *Absolute Ratings* table should not be used. If using a higher voltage system power supply, a voltage regulator can be used to step down to 3.3 V. Decoupling capacitors should be used to reduce noise and improve power supply integrity. A 0.1-μF capacitor should be used on each power pin.

8.4 Layout

8.4.1 Layout Guidelines

- RXP/N and TXP/N pairs should be routed with controlled 90-Ω differential impedance ($\pm 15\%$).
- Keep away from other high speed signals.
- Intra-pair routing should be kept to within 2mils.
- Length matching should be near the location of mismatch.
- Each pair should be separated at least by 3 times the signal trace width.
- The use of bends in differential traces should be kept to a minimum. When bends are used, the number of left and right bends should be as equal as possible and the angle of the bend should be ≥ 135 degrees. This will minimize any length mismatch causes by the bends and therefore minimize the impact bends have on EMI.
- Route all differential pairs on the same of layer.
- The number of VIAS should be kept to a minimum. It is recommended to keep the VIAS count to 2 or less.
- Keep traces on layers adjacent to ground plane.
- Do not route differential pairs over any plane split.
- Adding test points will cause impedance discontinuity; and will therefore, negatively impact signal performance. If test points are used, they should be placed in series and symmetrically. They must not be placed in a manner that causes a stub on the differential pair.

- The 100-nF capacitors on the TXP and SSTXN nets must be placed close to the USB connector (Type A, Type B, and so forth).
- The ESD and EMI protection devices (if used) must also be placed as close as possible to the USB connector.
- Place voltage regulators as far away as possible from the differential pairs.
- To minimize crosstalk, TI recommends keeping high-speed signals away from each other. Each pair must be separated by at least 5 times the signal trace width. Separating with ground also helps minimize crosstalk.

8.4.2 Layout Example

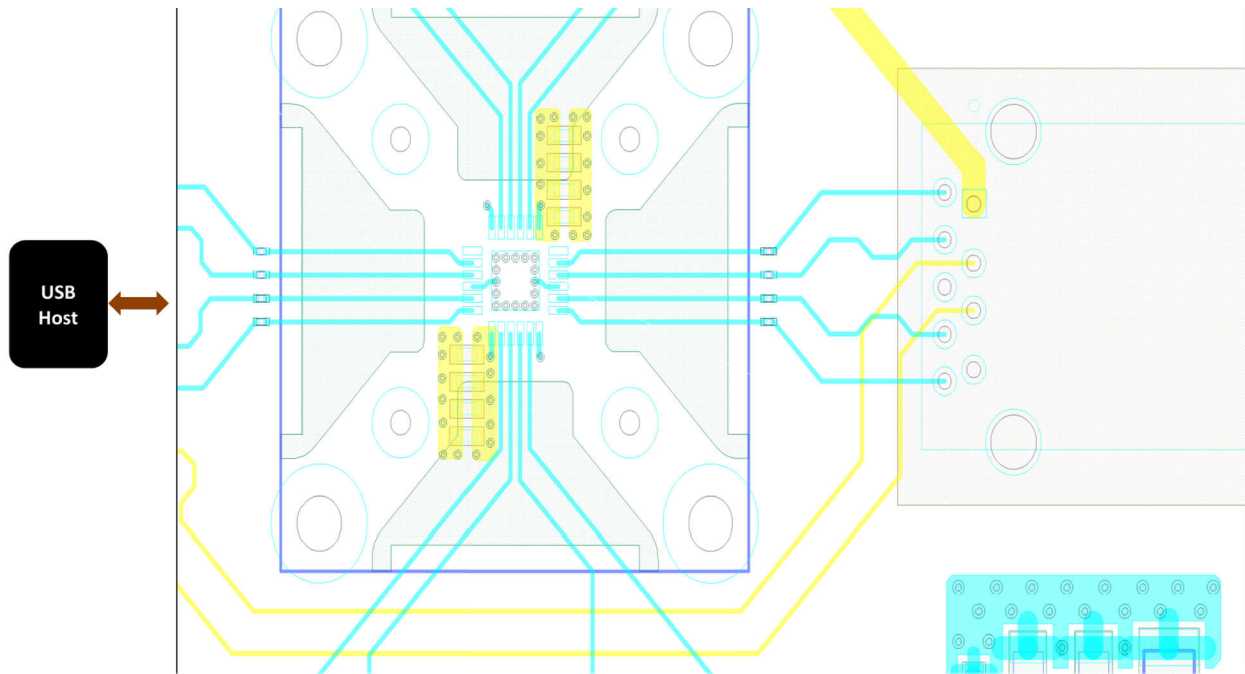


图 8-3. Example Layout

9 Device and Documentation Support

9.1 接收文档更新通知

要接收文档更新通知，请导航至 [ti.com](https://www.ti.com) 上的器件产品文件夹。点击 [通知](#) 进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

9.2 支持资源

TI E2E™ 中文支持论坛是工程师的重要参考资料，可直接从专家处获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题，获得所需的快速设计帮助。

链接的内容由各个贡献者“按原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的[使用条款](#)。

9.3 Trademarks

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9.4 静电放电警告



静电放电 (ESD) 会损坏这个集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理和安装程序，可能会损坏集成电路。

ESD 的损坏小至导致微小的性能降级，大至整个器件故障。精密的集成电路可能更容易受到损坏，这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

9.5 术语表

TI 术语表 本术语表列出并解释了术语、首字母缩略词和定义。

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TUSB522PIRGER	Active	Production	VQFN (RGE) 24	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	TUSB 522P
TUSB522PIRGET	Active	Production	VQFN (RGE) 24	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	TUSB 522P
TUSB522PRGER	Active	Production	VQFN (RGE) 24	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	0 to 70	TUSB 522P
TUSB522PRGET	Active	Production	VQFN (RGE) 24	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	0 to 70	TUSB 522P

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "-" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TUSB522PIRGER	VQFN	RGE	24	3000	330.0	12.4	4.25	4.25	1.15	8.0	12.0	Q2
TUSB522PIRGET	VQFN	RGE	24	250	180.0	12.4	4.25	4.25	1.15	8.0	12.0	Q2
TUSB522PRGER	VQFN	RGE	24	3000	330.0	12.4	4.25	4.25	1.15	8.0	12.0	Q2
TUSB522PRGET	VQFN	RGE	24	250	180.0	12.4	4.25	4.25	1.15	8.0	12.0	Q2

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

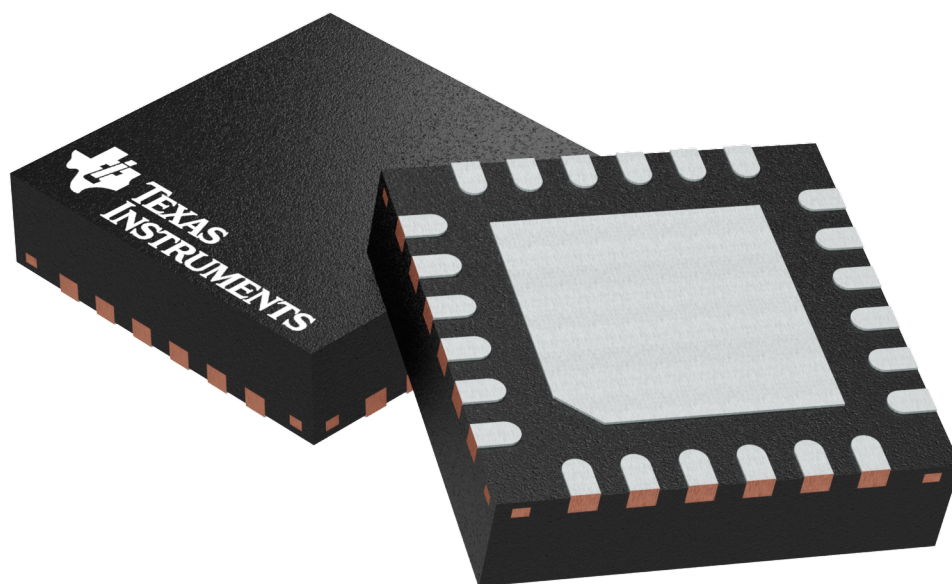
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TUSB522PIRGER	VQFN	RGE	24	3000	356.0	356.0	35.0
TUSB522PIRGET	VQFN	RGE	24	250	210.0	185.0	35.0
TUSB522PRGER	VQFN	RGE	24	3000	356.0	356.0	35.0
TUSB522PRGET	VQFN	RGE	24	250	210.0	185.0	35.0

RGE 24

GENERIC PACKAGE VIEW

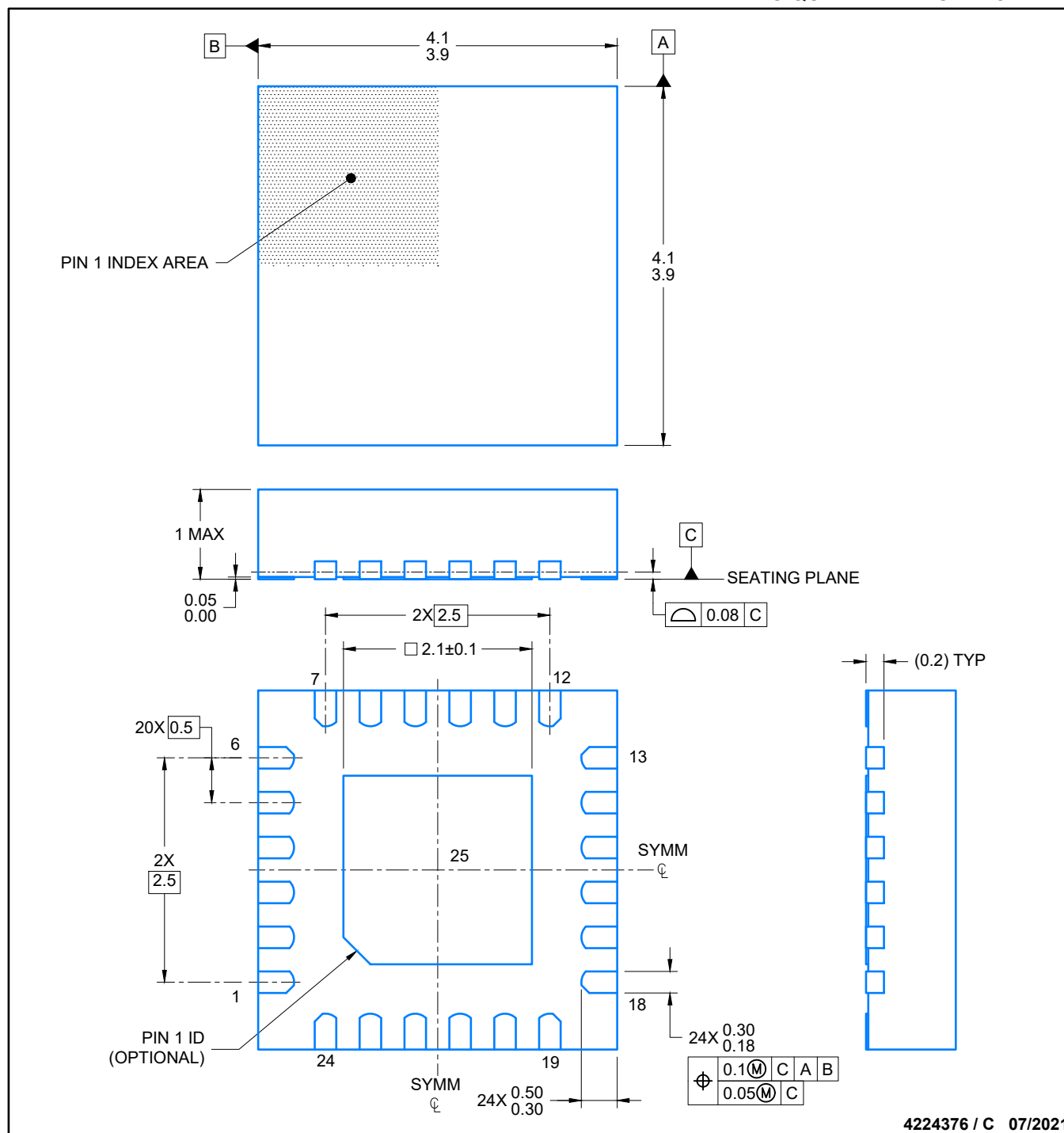
VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

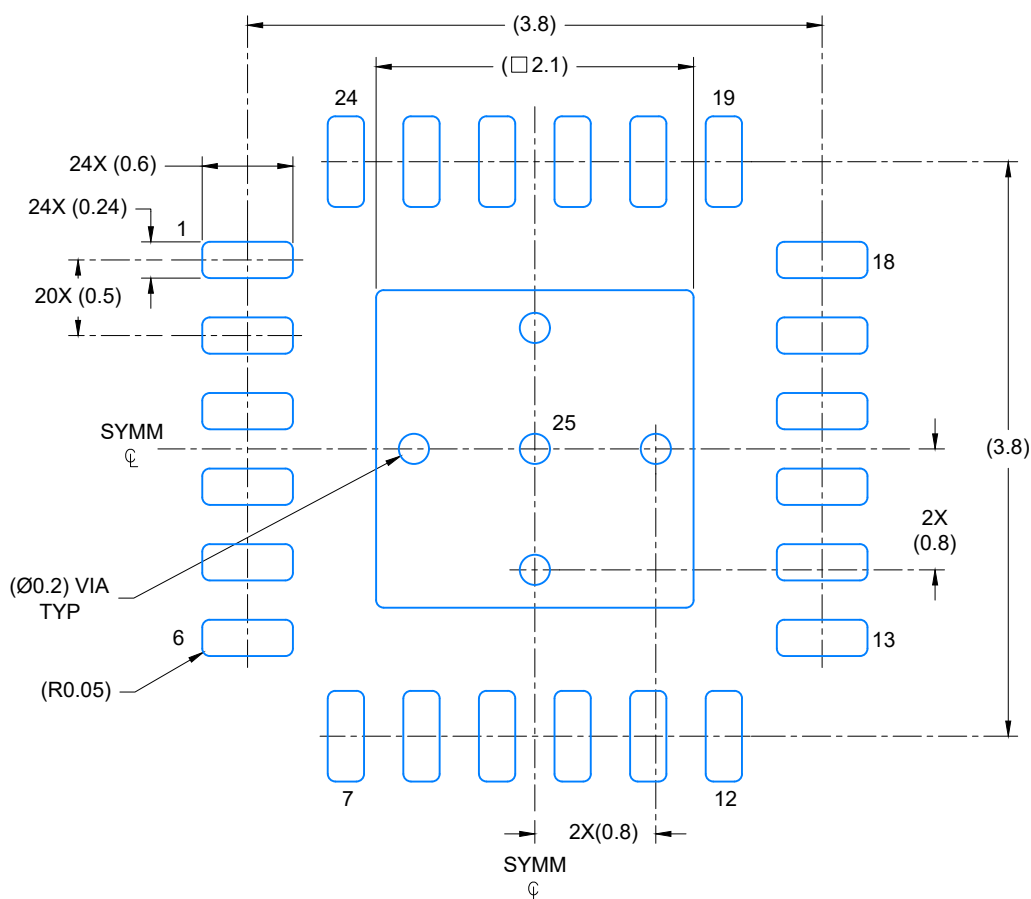
4204104/H



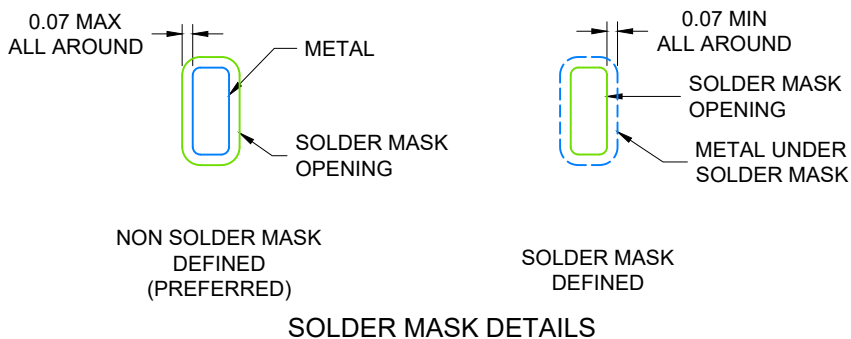
4224376 / C 07/2021

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



LAND PATTERN EXAMPLE
SCALE: 20X



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NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/sluea271).
5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

VQFN - 1 mm max height

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